Power MOSFET

–20 V, –5.6 A, μCool [™] Dual P–Channel, 2.0x2.0x0.55 mm UDFN Package

Features

- UDFN Package with Exposed Drain Pads for Excellent Thermal Conduction
- Low R_{DS(on)}
- Low Profile UDFN 2.0x2.0x0.55 mm for Board Space Saving
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- High Side Load Switch
- Reverse Current Protection
- Battery Switch
- Optimized for Power Management Applications for Portable Products, such as Cell Phones, PMP, DSC, GPS, and others

MAXIMUM RATINGS (T_J = 25° C unless otherwise stated)

Parameter			Symbol	Value	Units	
Drain-to-Source Voltage			V _{DSS}	-20	V	
Gate-to-Source Voltage			V _{GS}	±8.0	V	
Continuous Drain	,		I _D	-4.4	А	
Current (Note 1)	State	$T_A = 85^{\circ}C$		-3.2		
	t ≤ 5 s	$T_A = 25^{\circ}C$		-5.6		
Power Dissipa- tion (Note 1)	Steady State	T _A = 25°C	P _D	1.4	W	
	t ≤ 5 s	$T_A = 25^{\circ}C$		2.2		
Continuous Drain	Steady	T _A = 25°C	I _D	-2.8	А	
Current (Note 2)	State	T _A = 85°C		-2.0		
Power Dissipation (Note 2) $T_A = 25^{\circ}C$			PD	0.5	W	
Pulsed Drain Current $tp = 10 \ \mu s$			I _{DM}	-13	А	
Operating Junction and Storage Temperature			T _J , T _{STG}	-55 to 150	°C	
ESD (HBM, JESD22–A114) (MM, JESD22–A114)			V _{ESD}	1400 200	V	
Source Current (Body Diode) (Note 2)			۱ _S	-1.0	А	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface Mounted on FR4 Board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces) based on both FETs on.

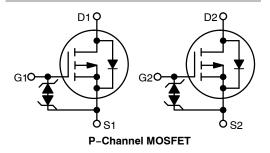
 Surface-mounted on FR4 board using the minimum recommended pad size of 30 mm², 1 oz. Cu based on both FETs on.



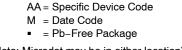
ON Semiconductor®

http://onsemi.com

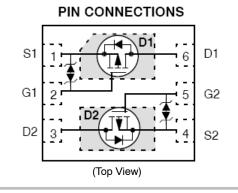
MOSFET				
V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX		
-20 V	50 mΩ @ –4.5 V			
	70 mΩ @ −2.5 V	-5.6 A		
	115 mΩ @ –1.8 V	0.071		
	175 mΩ @ –1.5 V			







(Note: Microdot may be in either location)



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

THERMAL RESISTANCE RATINGS

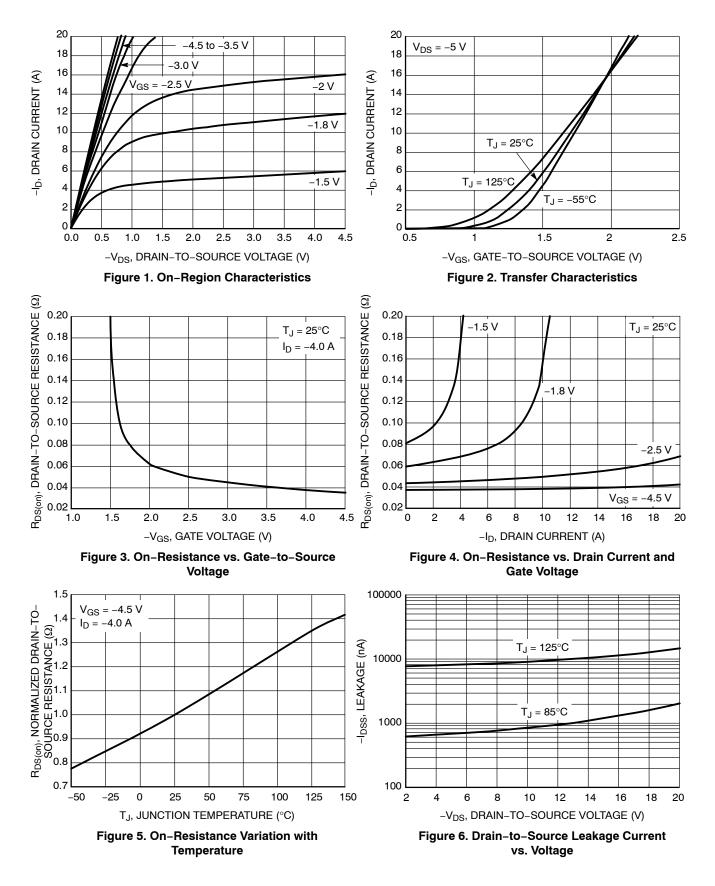
Parameter		Max	Units
Junction-to-Ambient – Steady State (Note 3)		91	°C/W
Junction-to-Ambient – t \leq 5 s (Note 3)		57	
Junction-to-Ambient – Steady State min Pad (Note 4)		228	

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

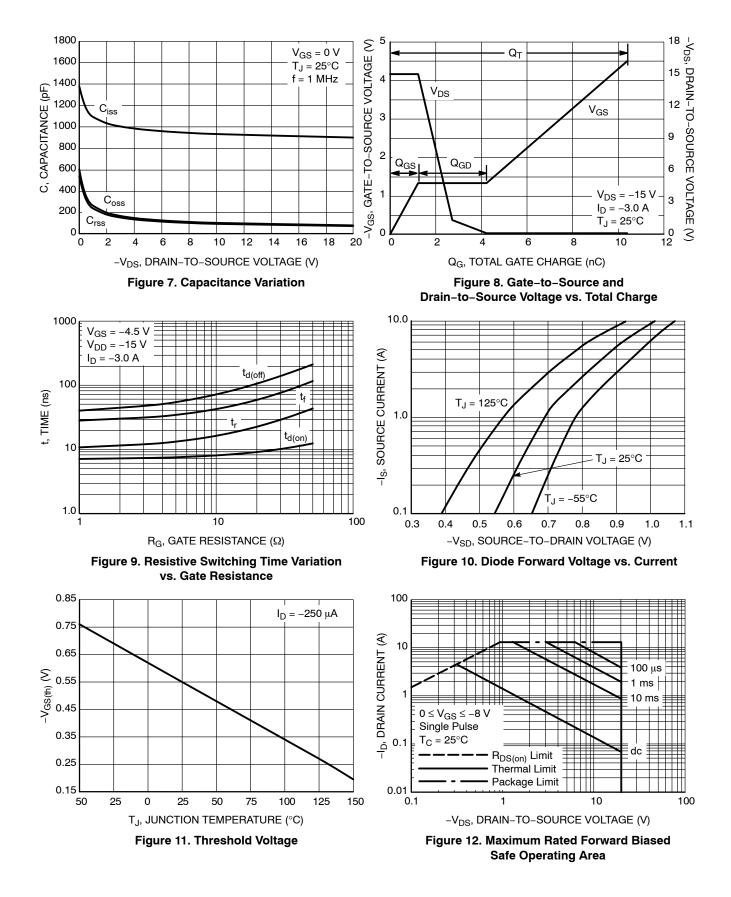
Parameter	Symbol	Test Co	ondition	Min	Тур	Max	Units
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = -250 μA		-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	$I_D = -250 \ \mu\text{A}$, ref to 25°C			-13		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = -20 V	$T_J = 25^{\circ}C$			-1.0	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±5.0 V				±5.0	μA
ON CHARACTERISTICS (Note 5)							-
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS},$	I _D = -250 μA	-0.4		-1.0	V
Negative Threshold Temp. Coefficient	V _{GS(TH)} /T _J				3.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = -4.5 V, I _D = -4.0 A			37	50	mΩ
		V _{GS} = -2.5	V, I _D = -3.0 A		46	70	
		V _{GS} = -1.8 '	V, I _D = -2.0 A		63	115	
		V _{GS} = -1.5 '	V, I _D = -1.0 A		86	175	
Forward Transconductance	9 FS	$V_{DS} = -5.0 \text{ V}, \text{ I}_{D} = -3.0 \text{ A}$			16		S
CHARGES AND CAPACITANCES				•			
Input Capacitance	C _{ISS}				920		pF
Output Capacitance	C _{OSS}	V_{GS} = 0 V, f = 1 MHz, V_{DS} = -15 V			85		
Reverse Transfer Capacitance	C _{RSS}				80		
Total Gate Charge	Q _{G(TOT)}				10.4		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = -4.5 V, V _{DS} = -15 V; I _D = -3.0 A			0.5		-
Gate-to-Source Charge	Q _{GS}				1.2		
Gate-to-Drain Charge	Q _{GD}				3.0		
SWITCHING CHARACTERISTICS, VG	S = 4.5 V (Note 6	3)					
Turn-On Delay Time	t _{d(ON)}				7.0		ns
Rise Time	t _r	$V_{GS} = -4.5 \text{ V}, \text{V}_{DD} = -15 \text{ V}, \\ \text{I}_{D} = -3.0 \text{ A}, \text{R}_{G} = 1 \Omega$			12		
Turn-Off Delay Time	t _{d(OFF)}				39		
Fall Time	t _f				30		
DRAIN-SOURCE DIODE CHARACTER	RISTICS						
Forward Diode Voltage	VSD	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		-0.67	-1.0	V
			T _J = 125°C		-0.56		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dis/dt = 100 A/μs, I _S = −1.0 A			12.1		ns
Charge Time	t _a				6.4		1
Discharge Time	t _b				5.7		
Reverse Recovery Charge	Q _{RR}				4.0		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces) based on both FETs on. 4. Surface-mounted on FR4 board using the minimum recommended pad size of 30 mm², 1 oz. Cu based on both FETs on. 5. Pulse Test: pulse width \leq 300 µs, duty cycle \leq 2%. 6. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

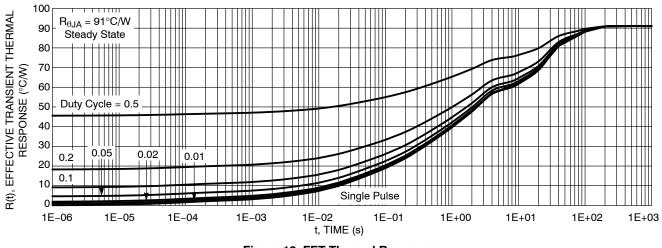


Figure 13. FET Thermal Response

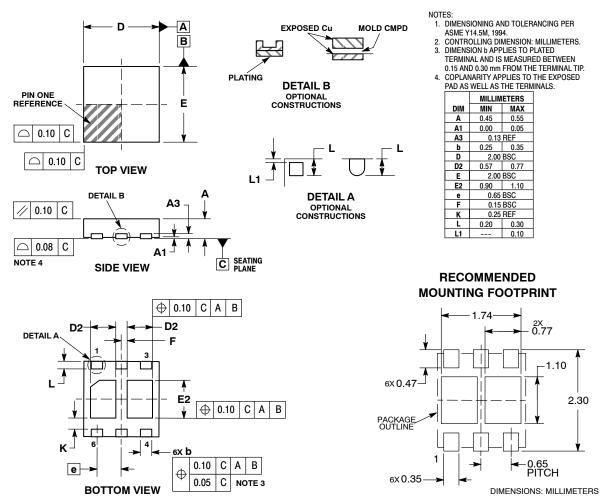
DEVICE ORDERING INFORMATION

Device	Package	Shipping [†]
NTLUD3A50PZTAG	UDFN6 (Pb-Free)	3000 / Tape & Reel
NTLUD3A50PZTBG	UDFN6 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

UDFN6 2x2, 0.65P CASE 517BF ISSUE B



μCool is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and **W** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemic.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components insystems intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death massociated with such unintended or unauthorized applicable copyright laws and is not for resade in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: NTLUD3A50PZTAG NTLUD3A50PZTBG